

# Oxidation resistance of hard boron-rich chalcogenides $B_6X$ and $B_{12}X$ ( $X = S, Se$ )

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Oxidation resistance of new boron-rich chalcogenides, orthorhombic  $B_6X$  and rhombohedral  $B_{12}X$  ( $X = S, Se$ ), was studied by thermal analysis (TG-MS). It has been established that in air boron-rich sulfides remains stable up to  $\sim 580^\circ\text{C}$ , while boron-rich selenides start to oxidize already at  $\sim 550^\circ\text{C}$ .

**Keywords:** boron-rich chalcogenides, oxidation resistance, thermal analysis.

Four new boron-rich chalcogenides – orthorhombic  $B_6S$  and  $B_6Se$  [1] and rhombohedral  $B_{12}S$  and  $B_{12}Se$  [2] – have been recently synthesized by direct reactions of the elements at high pressures and high temperatures. As follows from experimental [3] and theoretical [1] studies, all these compounds are characterized by high Vickers hardness (31-33 GPa) and, thus, could be of applied interest. However, in this regard their thermal and chemical stability are also rather important. In the present Letter we report the oxidation resistance of boron-rich chalcogenides.


Boron-rich chalcogenides (powders of grain size ranging from 1 to 10  $\mu\text{m}$ ) have been synthesized by direct reactions of the elements in a toroid-type high-pressure apparatus according to the methods described elsewhere [1,2]. X-ray diffraction study (TEXT 3000 Inel,  $\text{CuK}\alpha 1$  radiation) has shown that recovered samples contain well-crystallized single-phase boron-rich chalcogenides with lattice parameters close to the literature data [1,2]. Oxidation resistance in air at temperatures to  $1400^\circ\text{C}$  has been studied at a heating rate of 10 K/min by simultaneous thermogravimetric (TG) and mass spectroscopy (MS) analysis using Netzsch STA 409 PC/PG thermal analyzer coupled with QMS 403 Aëolos quadrupole mass spectrometer.

According to the results of thermogravimetric study, both boron-rich sulfides  $B_6S$  and  $B_{12}S$  remain stable in air up to  $580^\circ\text{C}$  (the onset temperatures from TG curves) (Fig. 1a). At higher temperatures, oxidation starts on the sample surface resulting in formation of boron ( $\text{B}_2\text{O}_3$ ) and sulfur ( $\text{SO}_2$ ) oxides. Mass spectrometry analysis of the evolved gases revealed the presence of parent  $\text{SO}_2$  ( $m/z = 64$ ) and fragment ion  $\text{SO}^+$  ( $m/z = 48$ ) for both boron-rich sulfides (see Fig. 2).

Orthorhombic  $B_6Se$  remains stable in air up to  $550^\circ\text{C}$  (the onset temperature from TG curve) (Fig. 1b). At higher temperatures, oxidation results in formation of boron ( $\text{B}_2\text{O}_3$ ) and selenium ( $\text{SeO}_2$ ) oxides. The oxidation resistance of  $B_{12}Se$  is remarkably higher, probably due to the lower selenium content of the phase. Mass spectrometry analysis of evolved gases in the case of boron-rich selenides was not possible due to the high sublimation temperature of  $\text{SeO}_2$  ( $> 315^\circ\text{C}$  [4]).

Thus, despite the high hardness of new boron-rich chalcogenides, their relatively low oxidation resistance may somewhat limit their applicability.

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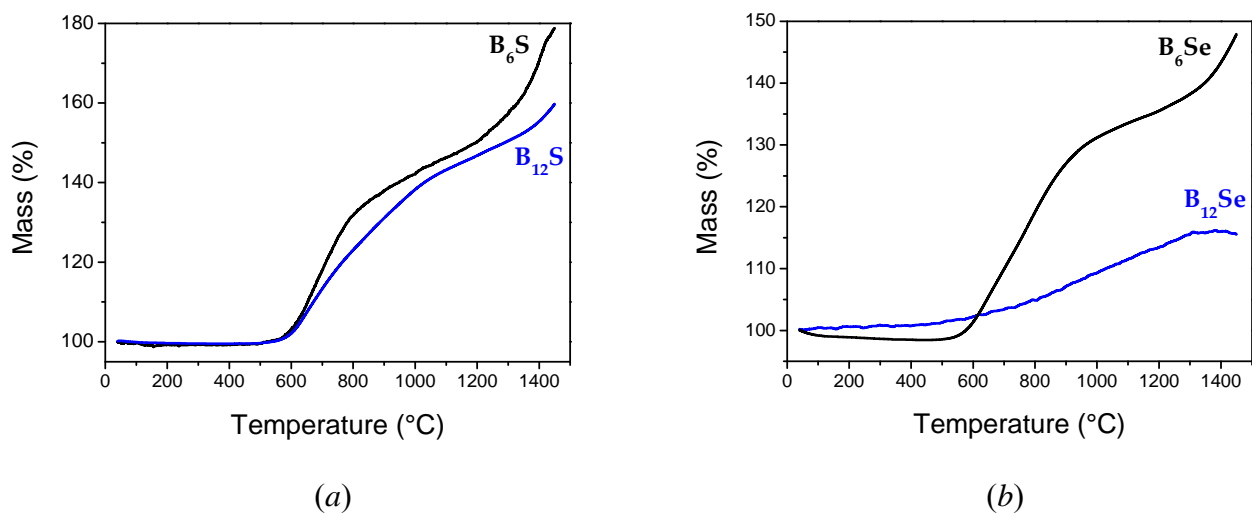


Fig. 1 Thermogravimetric data (in air) for boron-rich sulfides (a) and selenides (b).

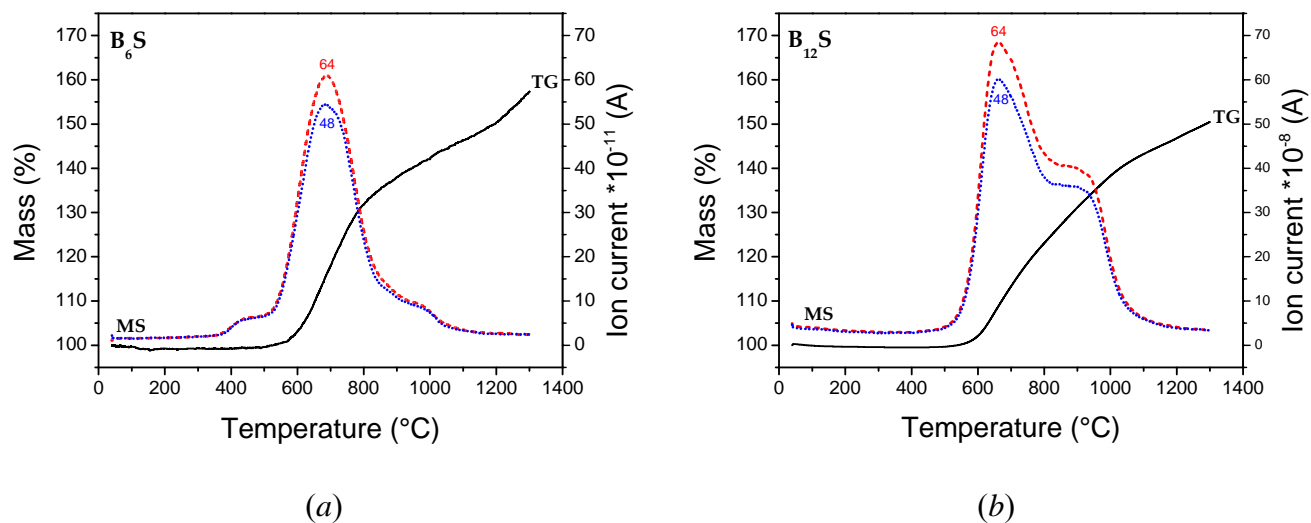


Fig. 2 Thermogravimetric (TG) and ion detection (MS) curves of boron-rich sulfides  $B_6S$  (a) and  $B_{12}S$  (b). Dashed and dotted lines correspond to mass/charge ratios 64 and 48.